

Japanese Journal of Applied Physics

VOLUME 20. 1981

Published Monthly with the Cooperation of
the Physical Society of Japan and the Japan Society of Applied Physics

Publication Board (Apr. 1981—Mar. 1982)

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Japanese Journal of Applied Physics

DAINI TOYOKAIJI BUILDING

24-8, SHINBASHI 4-CHOME, MINATO-KU

TOKYO 105 JAPAN

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This publication is partially supported
by the Grant-in-Aid for Scientific Research
from the Ministry of Education, Science and Culture.

JAPANESE JOURNAL OF APPLIED PHYSICS

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ST•WO	Method of Evaluating Tilt Domain in a Twisted Nematic Cell	Takao UMEDA, Takao MIYASHITA, Yasuyuki TSUTSUMI and Fumio NAKANO	2025
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Proceedings of
the 12th Conference on Solid State Devices

Tokyo, 1980

(published in February 1981)

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Proceedings of

The 2nd Photovoltaic Science and Engineering Conference in Japan

Tokyo, 1980

(published in June 1981)

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Proceedings of

The 1st Symposium on Ultrasonic Electronics

Tokyo, 1980

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For further details, see the Vol. 21, No. 1 issue.

Abbreviation of Subject Classification

AT	Atomic and Molecular Physics	MG	Magnetism, Magnetic Materials and Devices
ST	Structure of Matter	WO	Waves and Optics
CR	Crystal Growth and Phase Transformations	SE	Semiconductors
SF	Surface and Films	SD	Semiconductor Devices
MP	Mechanical Properties	QE	Quantum Electronics
TP	Statistical and Thermal Properties	NU	Nucleonics and Plasma Physics
EP	Electronic and Electrical Properties	TI	Techniques, Instrument and System
OP	Optical Properties	MI	Miscellaneous

Japanese Journal of Applied Physics Vol. 20 (1981), No. 12 [1981 年 12 月号]

発行所	応用物理学欧文誌刊行会	105 東京都港区新橋 4-24-8	1981 年 12 月 5 日 発行 (月刊)
発行者	八 木 利 夫	第二東洋海ビル (2 階)	
		電話 03-432-4308 (代表)	
印刷所	小宮山印刷工業株式会社	162 東京都新宿区天神町 78 番地	国内定価 1部 2,600 円 (送料共) 年間 26,000 円